

**Belita Koiller**Endereço para acessar este CV: <http://lattes.cnpq.br/7598434387418698>

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Resumo informado pelo autor

Possui graduação em Física pela Pontifícia Universidade Católica do Rio de Janeiro (1971) e doutorado em Física pela Universidade da Califórnia em Berkeley (1976). Atualmente é Profa. Titular da Universidade Federal do Rio de Janeiro. Tem experiência na área de Física, com ênfase em Física da Matéria Condensada, atuando principalmente nos seguintes temas: física de semicondutores, nanoestruturas, computação quântica e propriedades eletrônicas de sistemas desordenados. Entre os prêmios e distinções que recebeu destacam-se: Guggenheim Fellowship, membro titular da Academia Brasileira de Ciências, Grã Cruz da Ordem Nacional do Mérito Científico, laureada internacional (LA) em L'Oreal-Unesco Awards For Women in science, fellow of TWAS (The World Academy of Sciences).

(Texto informado pelo autor)

Links para Outras Bases:[SciELO - Artigos em texto completo](#) [Univ Federal do Rio de Janeiro](#) **Nome civil****Nome** Belita Koiller**Dados pessoais****Filiação** Samuel Krutman e Frida Krutman**Nascimento** 01/12/1949 - Rio de Janeiro/RJ - Brasil**Carteira de Identidade** 2037749 IFP - RJ - 06/10/1971**CPF** 528.389.197-68**Formação acadêmica/titulação**

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Produção

Produção bibliográfica

Artigos completos publicados em periódicos

- doi>** DUSKO, AMINTOR; DELGADO, ALAIN; SARAIVA, ANDRÉ; Koiller, Belita. Adequacy of Si:P chains as Fermi-Hubbard simulators. npj Quantum Information. **JCR**, v.4, p.1-1 - 1-5, 2018.
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